## **INK0200AC1**

High Speed Switching Silicon N-channel MOSFET

## **DESCRIPTION**

INK0200AC1 is a Silicon N-channel MOSFET.

This product is most suitable for use such as portable machinery, because of low voltage drive and low on resistance.

## **FEATURE**

- •Input impedance is high, and not necessary to consider a drive electric current.
- ·High drain current. ID=1A
- •Vth is low, and drive by low voltage is possible. Vth=0.4~1.3V
- •Low on Resistance. RDS(ON)= $0.2 \Omega$  (Typ)
- ·High speed switching.
- •Small package for easy mounting.

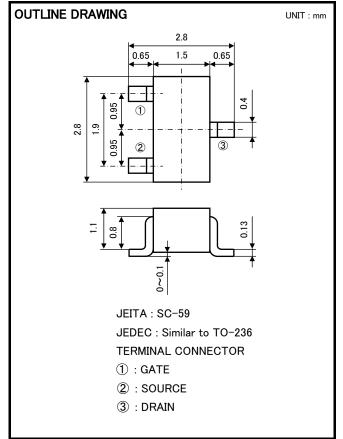
## **APPLICATION**

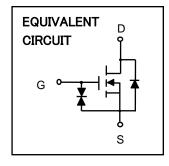
Switching

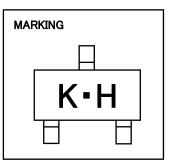
## MAXIMUM RATINGS (Ta=25°C)

Parameter	Symbol	Rating	Unit	
Drain-Source Voltage	VDSS	60	V	
Gate-Source Voltage	Vgss	±10	V	
Drain Current (DC)	ĪD	1	Α	
Drain Current (Pulse) *	<b>I</b> DP	4	Α	
Total Power Dissipation	PD	200	mW	
Channel Temperature	Tch	+150	°C	
Storage Temperature	Tstg	<b>-55∼+150</b>	°C	

\* Pw $\leq$ 10  $\mu$  s, Duty cycle $\leq$ 1%



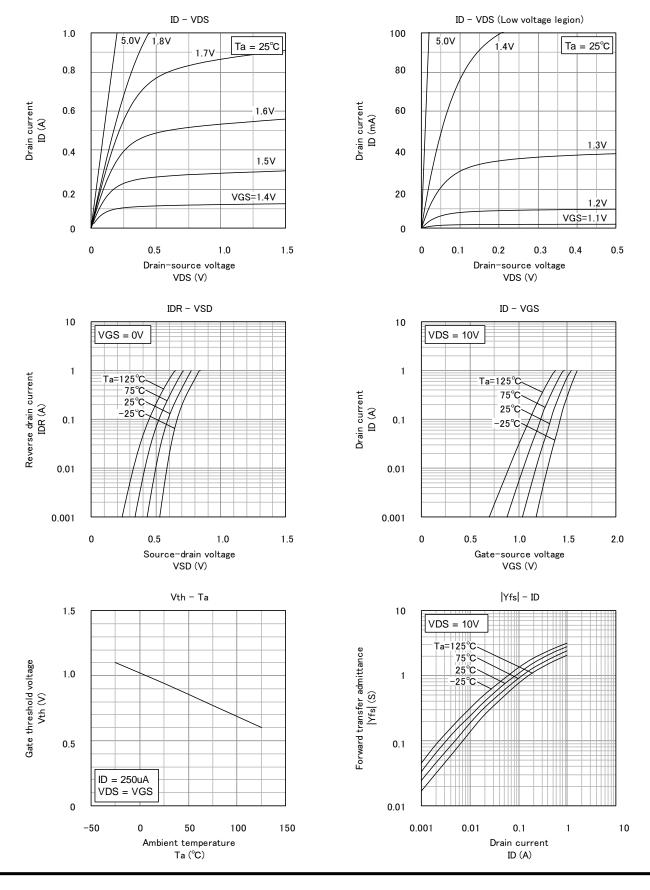




## ELECTRICAL CHARACTERISTICS (Ta=25°C)

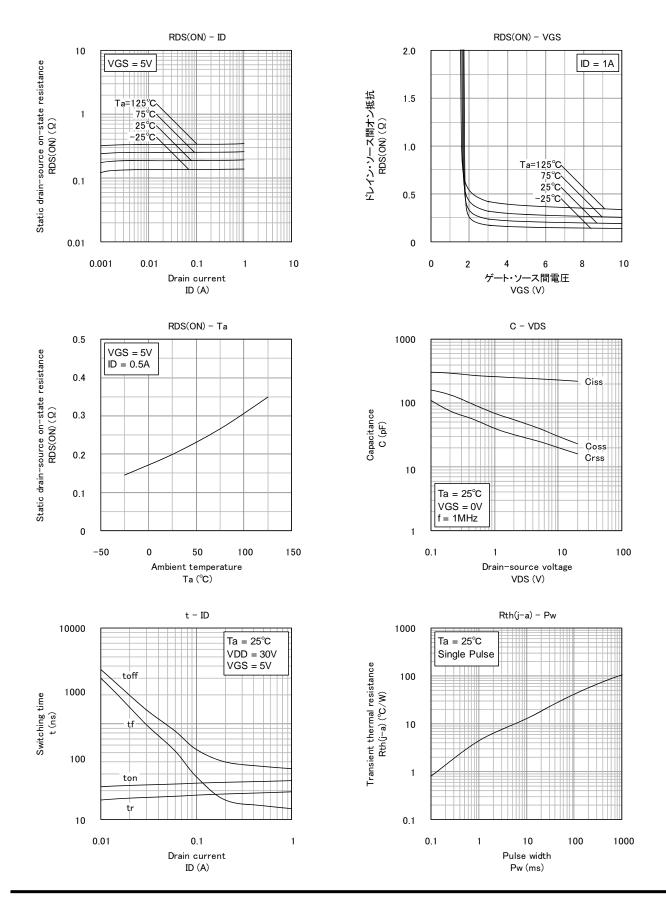
Parameter	Symbol	Test Condition	Limit			Unit
		Test Condition	Min	Тур	Max	Unit
Drain-Source Breakdown Voltage	V(BR)DSS	$I_{D}=100  \mu$ A, $V_{GS}=0V$	60	_	_	٧
Gate-Source Leak Current	Igss	$V_{GS}=\pm 10V$ , $V_{DS}=0V$	ı	_	±10	μΑ
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =60V, V <sub>GS</sub> =0V	ı	-	1	μΑ
Gate Threshold Voltage	Vth	$I_D=250 \mu$ A, $V_{DS}=V_{GS}$	0.4	-	1.3	٧
Forward Transfer Admittance	Yfs	$V_{DS}$ =10V, $I_{D}$ =1A	-	3.0	-	S
Static Drain-Source On-State Resisitance	RDS(ON)	I <sub>D</sub> =0.5A, V <sub>GS</sub> =5.0V	-	0.20	_	Ω
Input Capacitance	Ciss	\/ =10\/ \/ =0\/ (=1MI)	-	230	_	pF
Output Capacitance	Coss	$V_{DS}$ =10V, $V_{GS}$ =0V, f=1MHz	-	30	-	pF
Swithing Time	ton	V <sub>DD</sub> =30V, I <sub>D</sub> =1A	-	25	-	ns
	toff	V <sub>GS</sub> =0∼5V	-	35	_	ns

## TYPICAL CHARACTERISTICS



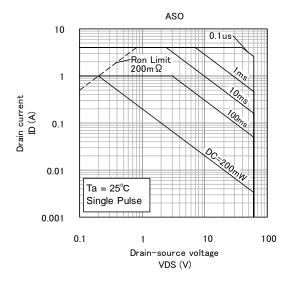
# **INK0200AC1**

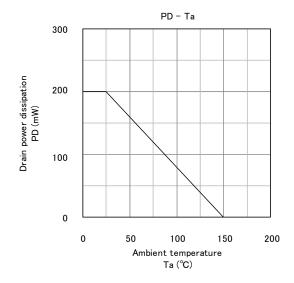
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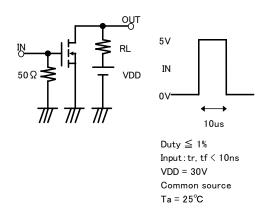
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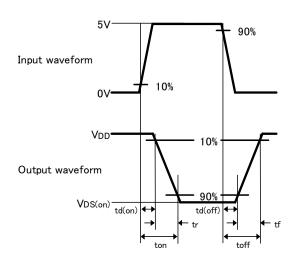
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## Switching time test condition







## Keep safety first in your circuit designs!

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